

CD40174B Types

CMOS Hex 'D'-Type Flip-Flop

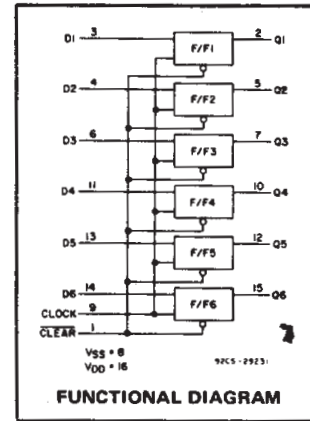
High-Voltage Types (20-Volt Rating)

■ CD40174B consists of six identical 'D'-type flip-flops having independent DATA inputs. The CLOCK and CLEAR inputs are common to all six units. Data is transferred to the Q outputs on the positive-going transition of the clock pulse. All six flip-flops are simultaneously reset by a low level on the CLEAR input.

The CD40174B types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

Features:

- 5-V, 10-V, and 15-V parametric rating
- Standardized symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μ A at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package-temperature range):
 1 V at $V_{DD} = 5$ V
 2 V at $V_{DD} = 10$ V
 2.5 V at $V_{DD} = 15$ V
- Meets all requirements of JEDEC Tentative Standard No. 13A, "Standard Specifications for Description of 'B' Series CMOS Devices"



Applications:

- Shift Registers
- Buffer/Storage Registers
- Pattern Generators

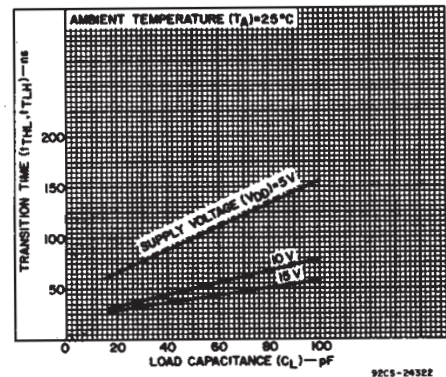
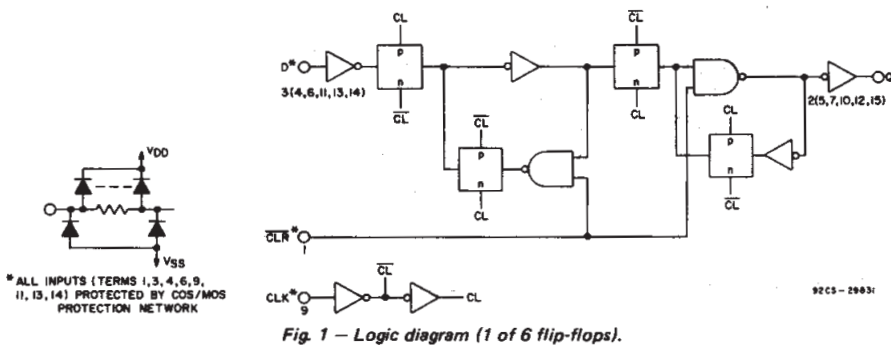
MAXIMUM RATINGS, Absolute-Maximum Values:

- DC SUPPLY-VOLTAGE RANGE, (V_{DD})
 Voltages referenced to V_{SS} Terminal) -0.5V to +20V
- INPUT VOLTAGE RANGE, ALL INPUTS -0.5V to $V_{DD} + 0.5$ V
- DC INPUT CURRENT, ANY ONE INPUT ± 10 mA
- POWER DISSIPATION PER PACKAGE (P_D):
 For $T_A = -55^\circ\text{C}$ to $+100^\circ\text{C}$ 500mW
 For $T_A = +100^\circ\text{C}$ to $+125^\circ\text{C}$ Derate Linearly at 12mW/ $^\circ\text{C}$ to 200mW
- DEVICE DISSIPATION PER OUTPUT TRANSISTOR
 FOR $T_A =$ FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
- OPERATING-TEMPERATURE RANGE (T_A) -55°C to $+125^\circ\text{C}$
- STORAGE TEMPERATURE RANGE (T_{stg}) -65°C to $+150^\circ\text{C}$
- LEAD TEMPERATURE (DURING SOLDERING):
 At distance $1/16 \pm 1/32$ inch (1.59 ± 0.79 mm) from case for 10s max $+265^\circ\text{C}$

TRUTH TABLE FOR 1 OF 6 FLIP-FLOPS

INPUTS		OUTPUT	
CLOCK	DATA	CLEAR	Q
	0	1	0
	1	1	1
	X	1	NC
X	X	0	0

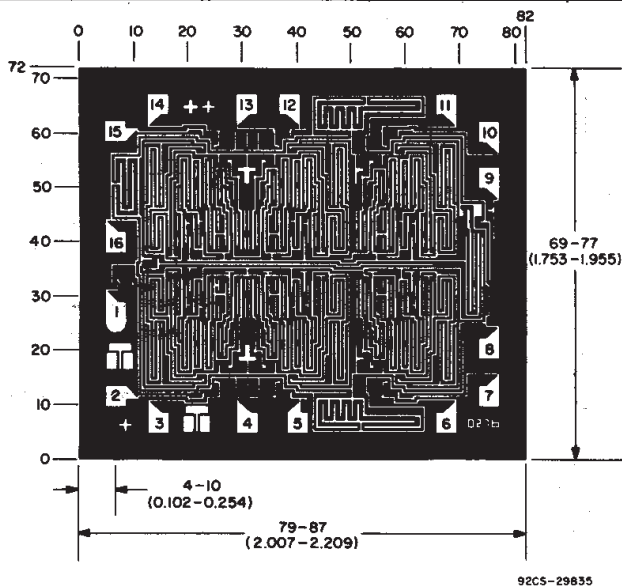
1 = High Level
 0 = Low Level
 X = Don't Care
 NC = No Change



CD40174B Types

RECOMMENDED OPERATING CONDITIONS at $T_A = 25^\circ\text{C}$, Except as Noted.
 For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V_{DD} (V)	LIMITS		UNITS
		Min.	Max.	
Supply-Voltage Range (For $T_A =$ Full Package-Temperature Range)	—	3	18	V
Data Setup Time, t_{SU}	5 10 15	40 20 10	— — —	ns
Data Hold Time, t_H	5 10 15	80 40 30	— — —	ns
Clock Input Frequency, f_{CL}	5 10 15	— dc —	3.5 6 8	MHz
Clock Input Rise or Fall Time, t_{rCL} , t_{fCL}	5 10 15	— — —	15 15 15	μs
Clock Input Pulse Width, t_{WL} , t_{WH}	5 10 15	130 60 40	— — —	ns
Clear Pulse Width, t_{WL}	5 10 15	100 50 40	— — —	ns
Clear Removal Time, t_{REM}	5 10 15	0 0 0	— — —	ns



Dimensions and pad layout for CD40174BH.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

The photographs and dimensions of each CMOS chip represent a chip when it is part of the wafer. When the wafer is separated into individual chips, the angle of cleavage may vary with respect to the chip face for different chips. The actual dimensions of the isolated chip, therefore, may differ slightly from the nominal dimensions shown. The user should consider a tolerance of -3 mils to $+16$ mils applicable to the nominal dimensions shown.

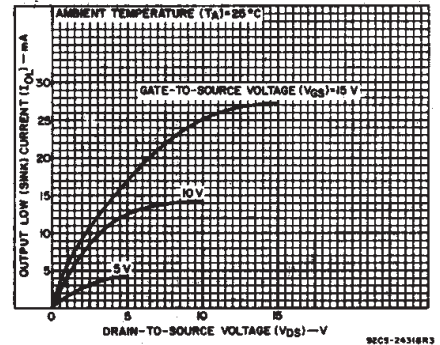


Fig. 3— Typical output low (sink) current characteristics.

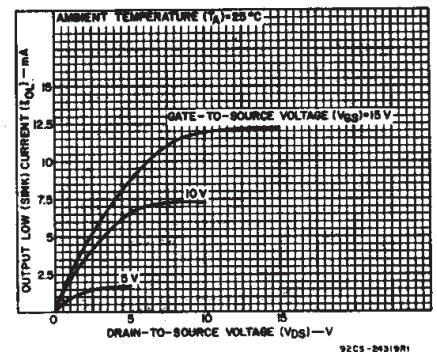


Fig. 4— Minimum output low (sink) current characteristics.

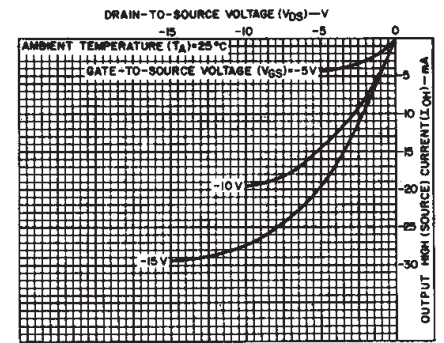


Fig. 5— Typical output high (source) current characteristics.

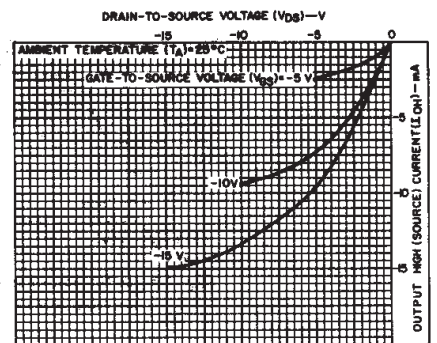


Fig. 6— Minimum output high (source) current characteristics.

3
COMMERCIAL CMOS
HIGH VOLTAGE ICs

CD40174B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
	V _O (V)	V _{IN} (V)	V _{DD} (V)	-55	-40	+85	+125	+25			
								Min.	Typ.	Max.	
Quiescent Device Current, I _{DD} Max.	—	0.5	5	1	1	30	30	—	0.02	1	μA
	—	0.10	10	2	2	60	60	—	0.02	2	
	—	0.15	15	4	4	120	120	—	0.02	4	
	—	0.20	20	20	20	600	600	—	0.04	20	
Output Low (Sink) Current I _{OL} Min.	0.4	0.5	5	0.64	0.61	0.42	0.36	0.51	1	—	mA
	0.5	0.10	10	1.6	1.5	1.1	0.9	1.3	2.6	—	
	1.5	0.15	15	4.2	4	2.8	2.4	3.4	6.8	—	
Output High (Source) Current, I _{OH} Min.	4.6	0.5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	—	mA
	2.5	0.5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	—	
	9.5	0.10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—	
Output Voltage: Low-Level, V _{OL} Max.	—	0.5	5	0.05			—	0	0.05	—	V
	—	0.10	10	0.05			—	—	0.05	—	
	—	0.15	15	0.05			—	0	0.05	—	
Output Voltage: High-Level, V _{OH} Min.	—	0.5	5	4.95			—	4.95	5	—	V
	—	0.10	10	9.95			—	9.95	10	—	
	—	0.15	15	14.95			—	14.95	15	—	
Input Low Voltage, V _{IL} Max.	0.5, 4.5	—	5	1.5			—	—	1.5	—	V
	1.9	—	10	3			—	—	3	—	
	1.5, 13.5	—	15	4			—	—	4	—	
Input High Voltage, V _{IH} Min.	0.5, 4.5	—	5	3.5			—	3.5	—	—	V
	1.9	—	10	7			—	7	—	—	
	1.5, 13.5	—	15	11			—	11	—	—	
Input Current I _{IN} Max.	—	0.18	18	±0.1	±0.1	±1	±1	—	±10 ⁻⁵	±0.1	μA

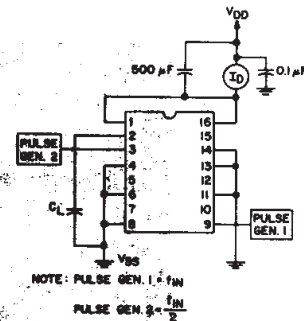
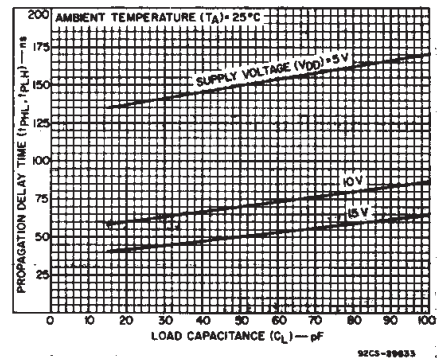
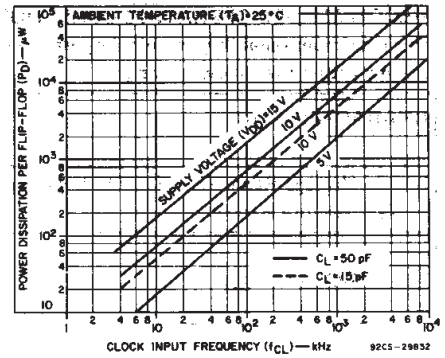
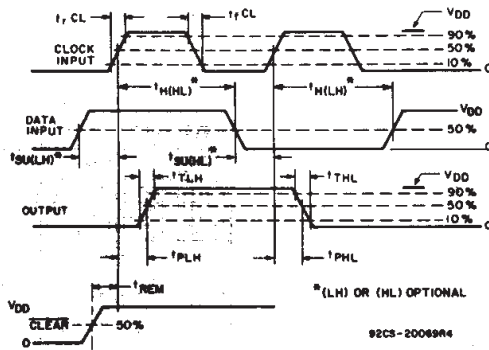


Fig. 9— Dynamic power dissipation test circuit.

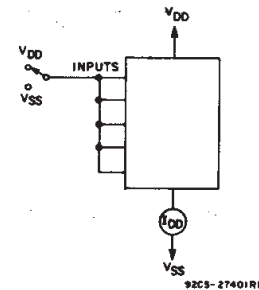


Fig. 11 — Quiescent device current test circuit.

CD40174B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$;
 Input $t_r, t_f = 20\text{ ns}$, $C_L = 50\text{ pF}$, $R_L = 200\text{ k}\Omega$

CHARACTERISTIC	TEST CONDITIONS V_{DD} (V)	LIMITS			UNITS
		Min.	Typ.	Max.	
Propagation Delay Time Clock to Output, t_{PHL}, t_{PLH}	5	—	150	300	ns
	10	—	70	140	
	15	—	50	100	
Clear to Output, t_{PHL}	5	—	100	200	ns
	10	—	50	100	
	15	—	40	80	
Transition Time, t_{THL}, t_{TLH}	5	—	100	200	ns
	10	—	50	100	
	15	—	40	80	
Minimum Pulse Width, Clock, t_{WL}, t_{WH}	5	—	65	130	ns
	10	—	30	60	
	15	—	20	40	
Clear, t_{WL}	5	—	50	100	ns
	10	—	25	50	
	15	—	20	40	
Minimum Data Setup Time, t_{SU}	5	—	20	40	ns
	10	—	10	20	
	15	—	0	10	
Minimum Data Hold Time, t_H	5	—	40	80	ns
	10	—	20	40	
	15	—	15	30	
Maximum Clock Frequency, f_{CL}	5	3.5	7	—	MHz
	10	6	12	—	
	15	8	16	—	
Maximum Clock Rise or Fall Time, t_{rCL}, t_{fCL}	5	15	—	—	μs
	10	15	—	—	
	15	15	—	—	
Input Capacitance, C_{IN}	Clear	—	25	40	pF
	All other	—	5	7.5	
Minimum Clear Removal Time, t_{REM}	5	—	-40	0	ns
	10	—	-15	0	
	15	—	-10	0	

3
 COMMERCIAL CMOS
 HIGH VOLTAGE ICs

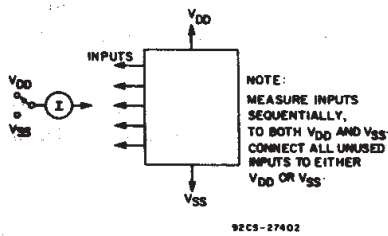


Fig. 12 - Input current test circuit.

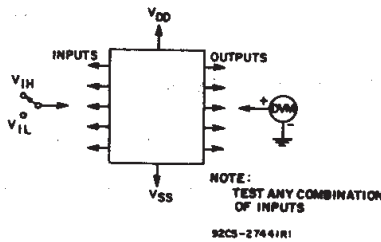
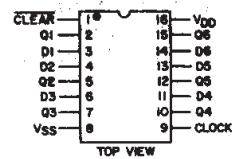


Fig. 13 - Input voltage test circuit.

TERMINAL ASSIGNMENT



IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.